
HM67S18258 Series

4M Synchronous Fast Static RAM (256k-words × 18-bits)

HITACHI

ADE-203-661B(Z)
Product Preview, Rev. 2
Nov. 18, 1997

Features

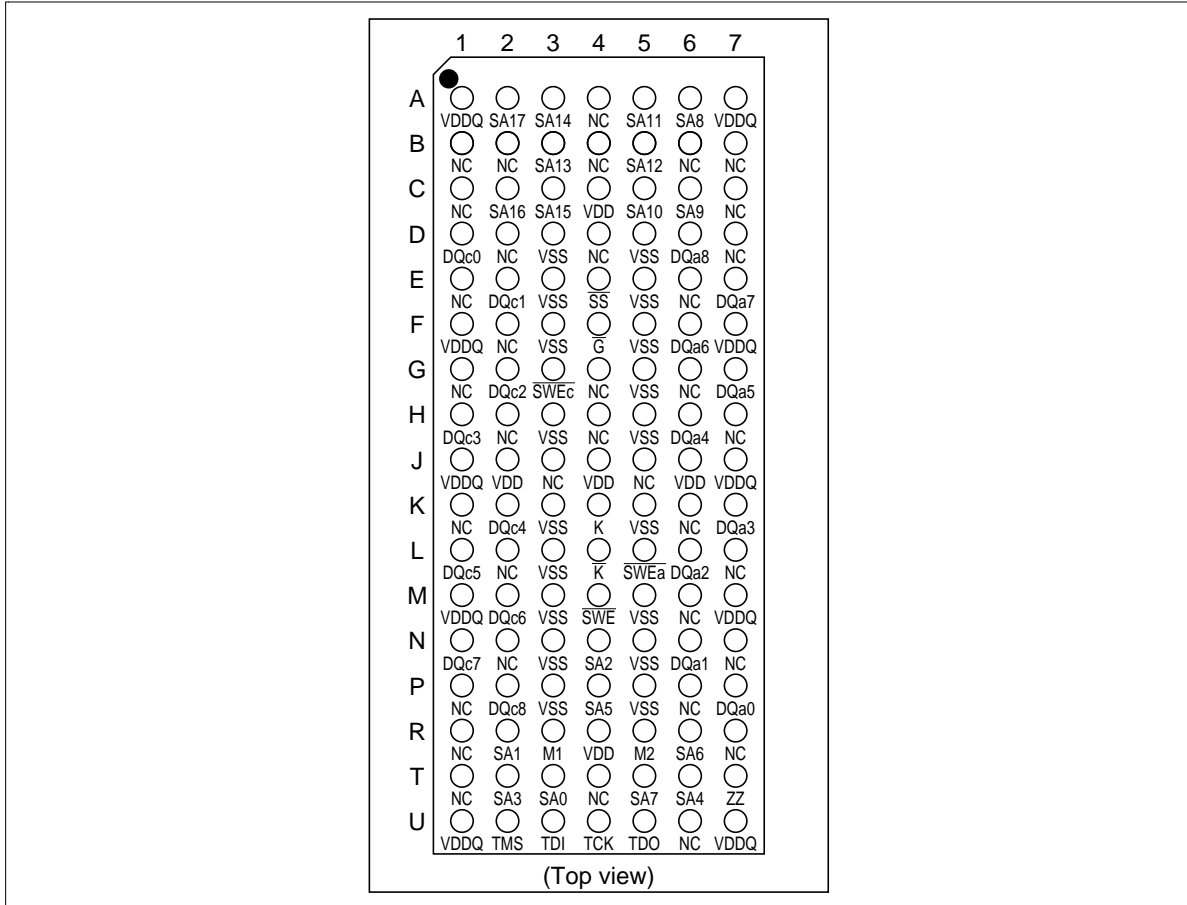
- 3.3V ± 5% Operation
- LVC MOS Compatible Input and Output
- Synchronous Operation
- Internal self-timed Late Write
- Asynchronous \bar{G} Output Control
- Byte Write Control
(2 byte write selects, one for each 9 bits)
- Power down mode is provided
- Differential PECL Clock Inputs
- Boundary Scan
- Protocol Single Clock Resister-Latch Mode

Ordering Information

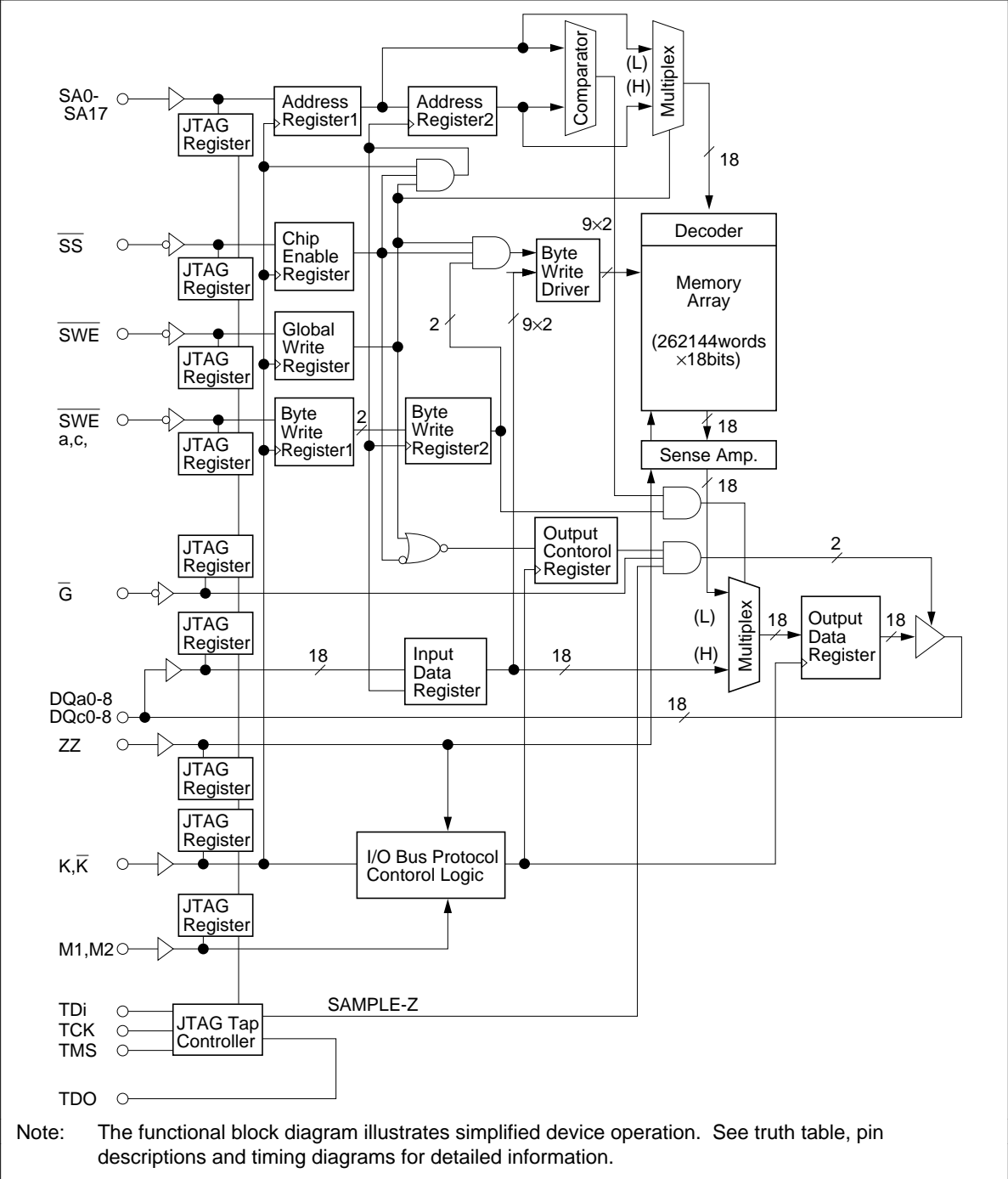
| Type Number | Cycle Time | Package |
|----------------|------------|---|
| HM67S18258BP-7 | 7.0 ns | 119 Bump 1.27 mm 14 mm × 22 mm BGA (BP-119A) |

HM67S18258 Series

Pin Arrangement



Block Diagram



HM67S18258 Series

Pin Descriptions

| Name | I/O Type | Descriptions | Note |
|--------------|----------|--------------------------------|-----------------------------|
| V_{DD} | | Power Supply | |
| V_{SS} | | Ground | |
| V_{DDQ} | | Output Power Supply | |
| K | Input | Input Clock | |
| \bar{K} | Input | Input Clock | |
| \bar{SS} | Input | Synchronous Chip Select | |
| \bar{SWE} | Input | Synchronous Write Enable | |
| SAn | Input | Synchronous Address | n = 0, 1, 2, ... 17 |
| $\bar{SWE}x$ | Input | Synchronous Byte Select | x = a, c |
| \bar{G} | Input | Asynchronous Output Enables | |
| ZZ | Input | Power Down Mode Select | |
| DQxm | I/O | Synchronous Data Input/Output | x = a, c m = 0, 1, 2, ... 8 |
| M1, M2 | Input | Output Protocol Mode Select | 1 |
| TMS | Input | Boundary Scan Test Mode Select | |
| TCK | Input | Boundary Scan Test Clock | |
| TDI | Input | Boundary Scan Test Data In | |
| TDO | Output | Boundary Scan Test Data Out | |
| NC | | No Connection | |

Notes: 1. There is 1 protocol with using mode pins. Mode control pins (M1, M2) are to be tied to either V_{DD} or V_{SS} . The state of the Mode control inputs must be set before power-up and must not change during device operation. Mode control inputs are not standard inputs and may not meet V_{IH} or V_{IL} specifications.

| M1 | M2 | Protocol |
|----------|----------|-----------------------------|
| V_{DD} | V_{SS} | Single Clock Register Latch |

Truth Table

| \overline{SS} | \overline{G} | \overline{SWE} | \overline{SWEa} | \overline{SWEc} | K | \overline{K} | Operation | DQa | DQc |
|-----------------|----------------|------------------|-------------------|-------------------|-----|----------------|---------------------|--------|--------|
| H | X | X | X | X | L-H | H-L | Dead (not selected) | High-Z | High-Z |
| L | H | H | X | X | L-H | H-L | Dead (Dummy read) | High-Z | High-Z |
| L | L | H | X | X | L-H | H-L | Read | Dout | Dout |
| L | X | L | L | L | L-H | H-L | Write | Din | Din |
| L | X | L | H | L | L-H | H-L | Write | High-Z | Din |
| L | X | L | L | H | L-H | H-L | Write | Din | High-Z |

- Notes: 1. X means don't care for synchronous inputs, and H or L for asynchronous inputs.
 2. \overline{SWE} , \overline{SS} , \overline{SWEa} , \overline{SWEc} , SA are sampled at the rising edge of K clock.

Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit | Note |
|------------------------|-------------|------------------------|------|------|
| Supply voltage | V_{DD} | -0.5 to +4.6 | V | 1 |
| Output Supply Voltage | V_{DDQ} | -0.5 to $V_{DD}+0.5$ | V | 1, 4 |
| Voltage on any pin | V_{IN} | -0.5 to $V_{DD}+0.5$ | V | 1, 4 |
| Operating Temperature | Ta | 0 to 70 (Tj max = 110) | °C | |
| Storage Temperature | Tstg (bias) | -55 to 125 | °C | |
| Input Latchup Current | I_{LI} | ±200 | mA | |
| Output Current per pin | Iout | ±25 | mA | |

- Notes: 1. All voltage are referenced to V_{SS} .
 2. Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted the Operation Conditions. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.
 3. These Bi-CMOS memory circuits have been designed to meet the DC and AC specifications shown in the tables after thermal equilibrium has been established.
 4. Not exceed 4.6 V
 5. Power Up Initialization

The following supply voltage application sequence is recommended: V_{SS} , V_{DD} then V_{DDQ} .

Remember according to the Absolute Maximum Ratings table, V_{DDQ} is not to exceed $V_{DD} + 0.5 V$, whatever the instantaneous value of V_{DD} .

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Recommended DC Operating Conditions ($T_a = 0$ to 70°C [T_j max = 110°C])

| Parameter | Symbol | Min | Typ | Max | Unit | Notes |
|--------------------------------|-----------------------|-------|-----|-----------------|------|-------|
| Supply voltage | V_{DD} | 3.135 | 3.3 | 3.465 | V | |
| Output Supply voltage | V_{DDQ} | 3.135 | 3.3 | 3.465 | V | 1 |
| | | 2.375 | 2.5 | 2.75 | V | 2 |
| Input voltage Logic High Level | V_{IH} | 2.0 | — | $V_{DDQ} + 0.3$ | V | 1 |
| Logic Low Level | V_{IL} | -0.5 | — | 0.8 | V | 1 |
| Logic High Level | V_{IH} | 1.85 | — | $V_{DDQ} + 0.3$ | V | 2 |
| Logic Low Level | V_{IL} | -0.5 | — | 1.15 | V | 2 |
| PECL Logic High Level | $V_{IH}(\text{PECL})$ | 2.135 | — | 2.420 | V | |
| PECL Logic Low Level | $V_{IL}(\text{PECL})$ | 1.490 | — | 1.825 | V | |

Note: 1. For $V_{DDQ} = 3.3$ V supply.
2. For $V_{DDQ} = 2.5$ V supply.

DC Characteristics ($T_a = 0$ to 70°C [T_j max 110°C], $V_{DD} = 3.3\text{V} \pm 5\%$)

| Parameter | Symbol | Min | Typ | Max | Unit | Note | |
|---|-----------------|----------|----------------------|-----|------------------------|--------------------------|--------------|
| Input Leakage Current | I_{LI} | -1 | — | 1 | μA | 1 | |
| Output Leakage Current | I_{LO} | -1 | — | 1 | μA | 2 | |
| PECL Input Leakage Current Low | I_{LI} (PECL) | | — | 50 | μA | | |
| PECL Input Leakage Current High | I_{LI} (PECL) | | — | 150 | μA | | |
| V_{DD} Operating Current excluding output drivers | I_{DD} | — | — | 600 | mA | 3 | |
| Power Dissipation including output drivers | P_d | — | — | 2.7 | W | 3, 8 | |
| Standby Current (Power down mode) | I_{SB} | — | — | 100 | mA | 5 | |
| Output Voltage | Logic Low | V_{OL} | 0 | — | 0.4 | V | 4 |
| | Logic High | V_{OH} | 2.4 $V_{DDQ}-0.4$ | — | V_{DDQ} V_{DDQ} | V V | 4, 6 4, 7 |

- Note:
- $0 \leq V_{in} \leq V_{DD}$
 - $0 \leq V_{I/O} \leq V_{DD}$, Tristate I/O
 - $I(I/O) = 0$ mA, Address increment read 50% / write 50%, $V_{DD} = V_{DD}$ max, Frequency = 125 MHz
 - $I_{OH} = -2$ mA or $I_{OL} = 2$ mA
 - All inputs (except clock) are held at either V_{SS} or V_{DDQ} , and ZZ is held at V_{DDQ}
 - for $V_{DDQ} = 3.3$ V supply
 - for $V_{DDQ} = 2.5$ V supply
 - Output Load Capacitance = 29 pF

Input Capacitance ($T_a = 25^\circ\text{C}$, $f = 1$ MHz)

| Parameter | Symbol | Min | Max | Unit | Pin Name | Note |
|---------------------------|------------|-----|-----|------|---|------|
| Address Input Capacitance | C_{INA} | — | 5 | pF | SAn, \overline{SS} , \overline{SWE} , \overline{SWEx} | 1 |
| Clock Input Capacitance | C_{INC} | — | 8 | pF | K, \overline{K} , \overline{G} | 1 |
| I/O Capacitance | C_{INIO} | — | 7 | pF | DQxm | 1 |

- Note: 1. This value is measured by sampling and not 100% tested.

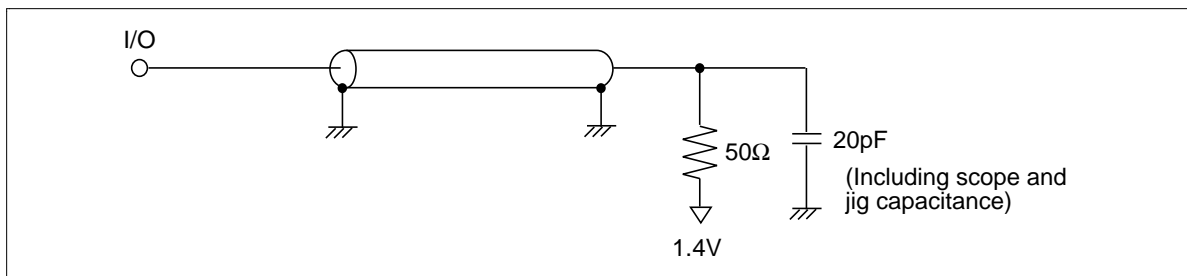
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AC Test Conditions

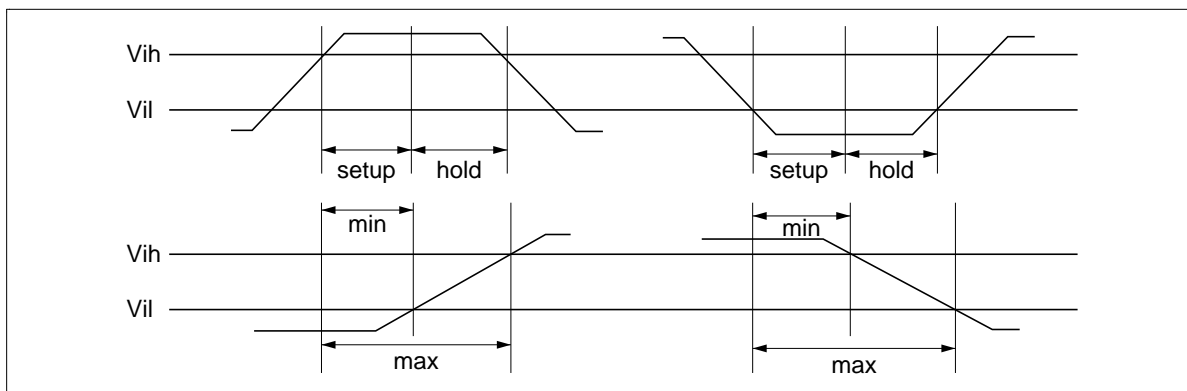
Note

| | | |
|--|--|---|
| • Temperature | $0^{\circ}\text{C} \leq T_a \leq 70^{\circ}\text{C}$ ($T_j \text{ max} = 110^{\circ}\text{C}$) | |
| • Input Reference Point for Differential Signals | Differential Cross-Over Point | |
| • Input pulse levels | 0 to 2.5 V | |
| • Clock Input pulse levels | 1.8 to 2.1 V | |
| • Input Rise/Fall Time | 0.5 to 1.5 ns (10% to 90%) | |
| • Clock input Rise/Fall Time | 0.3 to 1.0 ns (10% to 90%) | |
| • Output timing reference (v_{ih}/v_{il}) | 2.0 V/0.8 V for $V_{DDQ} = 3.3 \text{ V}$ | 1 |
| | 1.65 V/1.15 V for $V_{DDQ} = 2.5 \text{ V}$ | 1 |
| • Output load | See figures | |

Note: 1. These levels are efficient under open termination load condition.
 These v_{ih}/v_{il} levels under termination load will be determined by correlation between open load and termination load.



AC Timing Measurement



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AC Characteristics (Ta = 0° to 70°C [Tj max = 110°C], V_{DD}=3.3V± 5%)

Single Differential Clock Register-Latch Mode (M1 = V_{DD}, M2 = V_{SS})

| Parameter | Symbol | -7 | | Unit | Notes |
|------------------------|--------------------|-----|-----|------|--|
| | | Min | Max | | |
| Clock Control | | | | | |
| Clock Cycle | t _{KHKH} | 8.0 | — | ns | |
| Clock High Width | t _{KHKL} | 2.0 | — | ns | |
| Clock Low Width | t _{KLKH} | 2.0 | — | ns | |
| Read Control | | | | | |
| K Clock Access | t _{KHQV} | — | 7.0 | ns | |
| K Clock Access | t _{KLQV} | — | 3.0 | ns | |
| Output Enable Access | t _{GLQV} | — | 3.5 | ns | |
| K Low to Q Change | t _{KLQX} | 1.0 | — | ns | |
| Output Buffer Control | | | | | |
| K Low to Low-Z | t _{KLQX2} | 1.0 | — | ns | 1 |
| Output Enable to Low-Z | t _{GLQX} | 1.0 | — | ns | 1 |
| K Clock High to Hi-Z | t _{KHQZ} | 1.0 | 3.5 | ns | 2 |
| Output Enable to Hi-Z | t _{GHQZ} | 0.0 | 3.5 | ns | 2 |
| Setup Times | | | | | |
| Address Setup Time | t _{AVKH} | 0.5 | — | ns | SA, \overline{SS} , \overline{SWE} , |
| Data Setup Time | t _{DVKH} | 0.5 | — | ns | \overline{SWEa} , \overline{SWEc} |
| Hold Times | | | | | |
| Address Hold Time | t _{KHAX} | 1.0 | — | ns | SA, \overline{SS} , \overline{SWE} , |
| Data Hold Time | t _{KHDX} | 1.0 | — | ns | \overline{SWEa} , \overline{SWEc} |

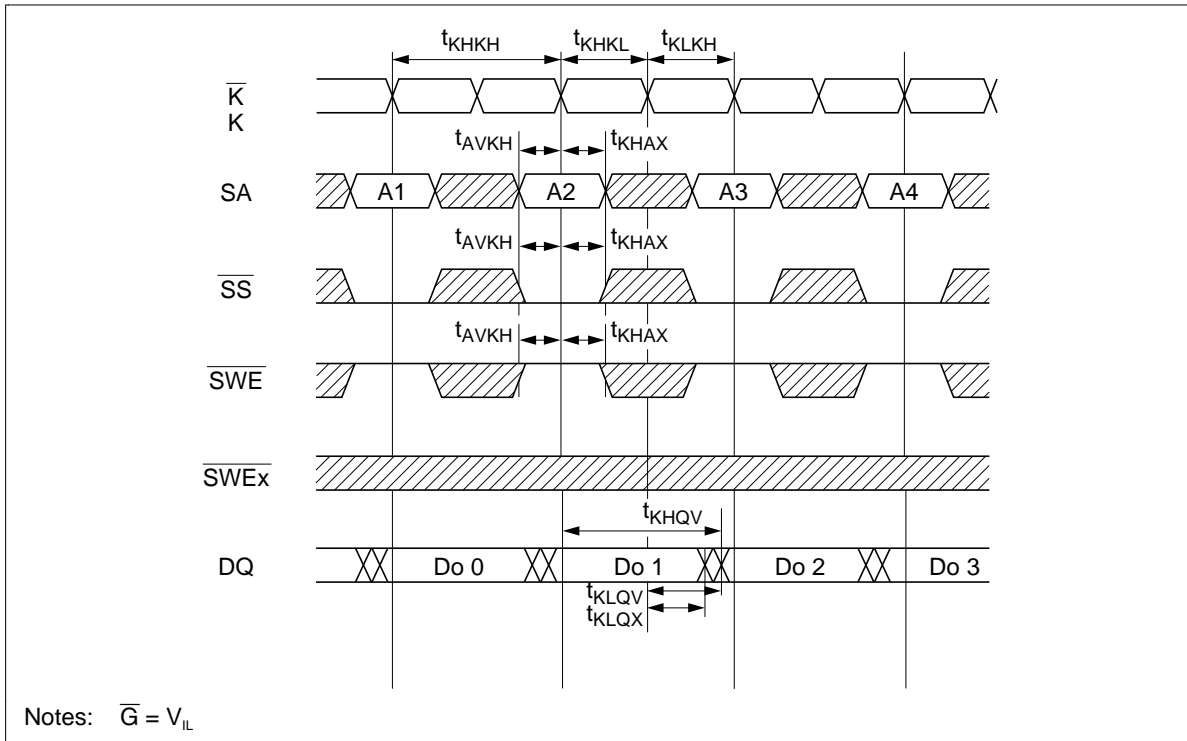
Notes: 1. Transition is measured ±200 mV from steady voltage with specified loading in Test Load.
 2. Transition is measured start point of output high impedance from output Low impedance.

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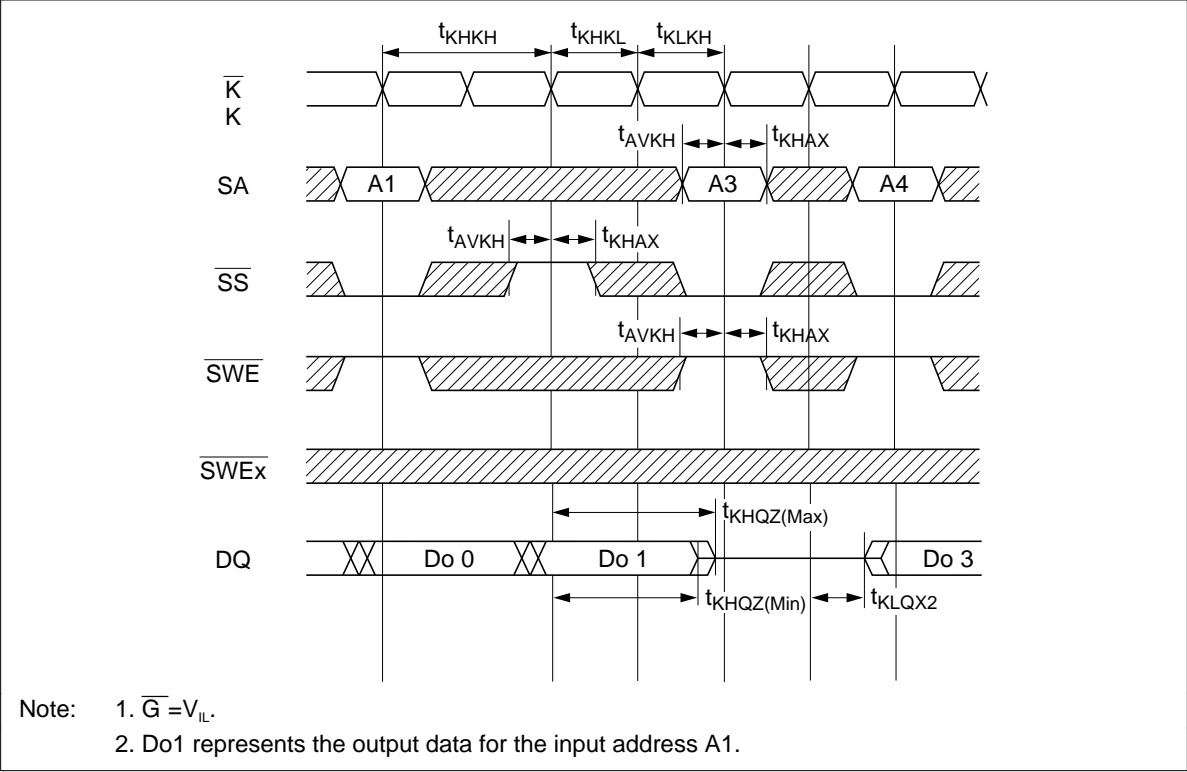
Timing Waveforms

Single Clock Register Latch Mode

Read Cycle 1

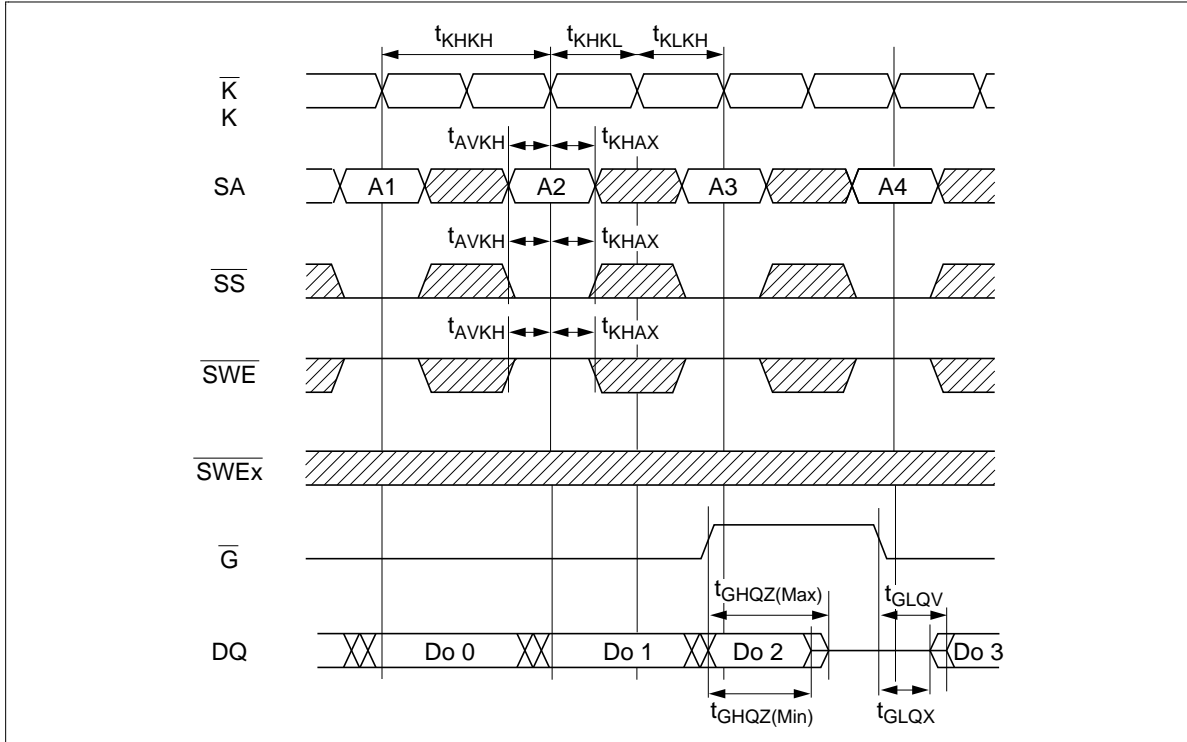


Read Cycle 2 (\overline{SS} Controlled)

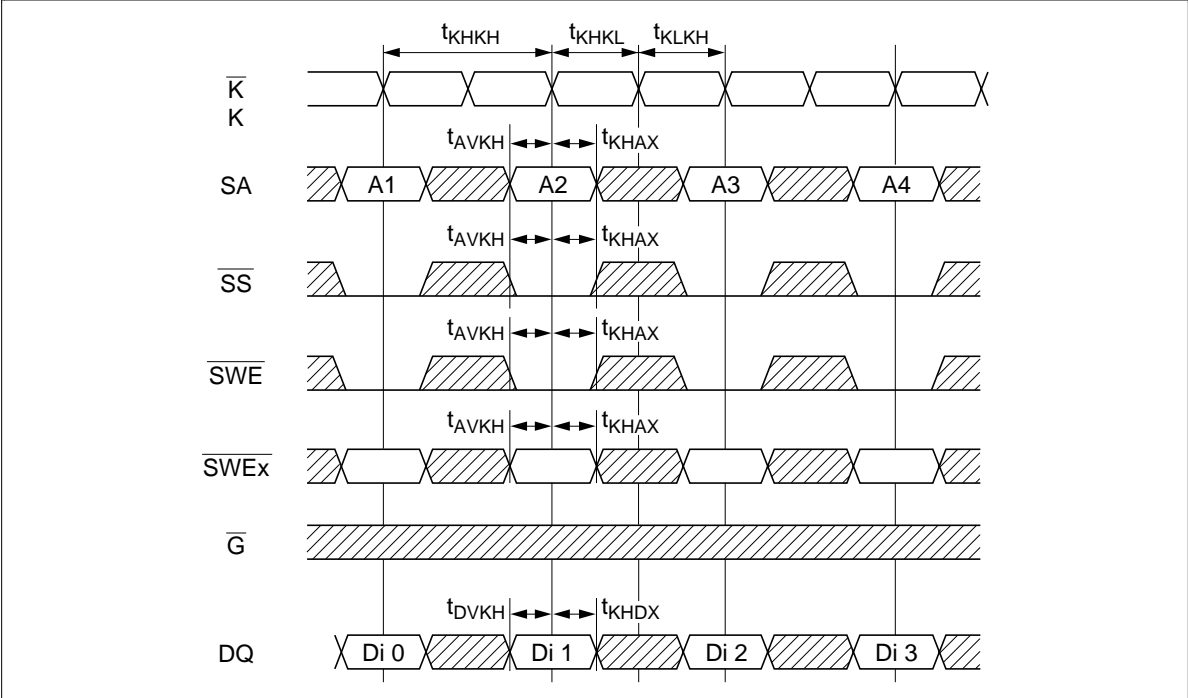


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Read Cycle 3 (\overline{G} Controlled)

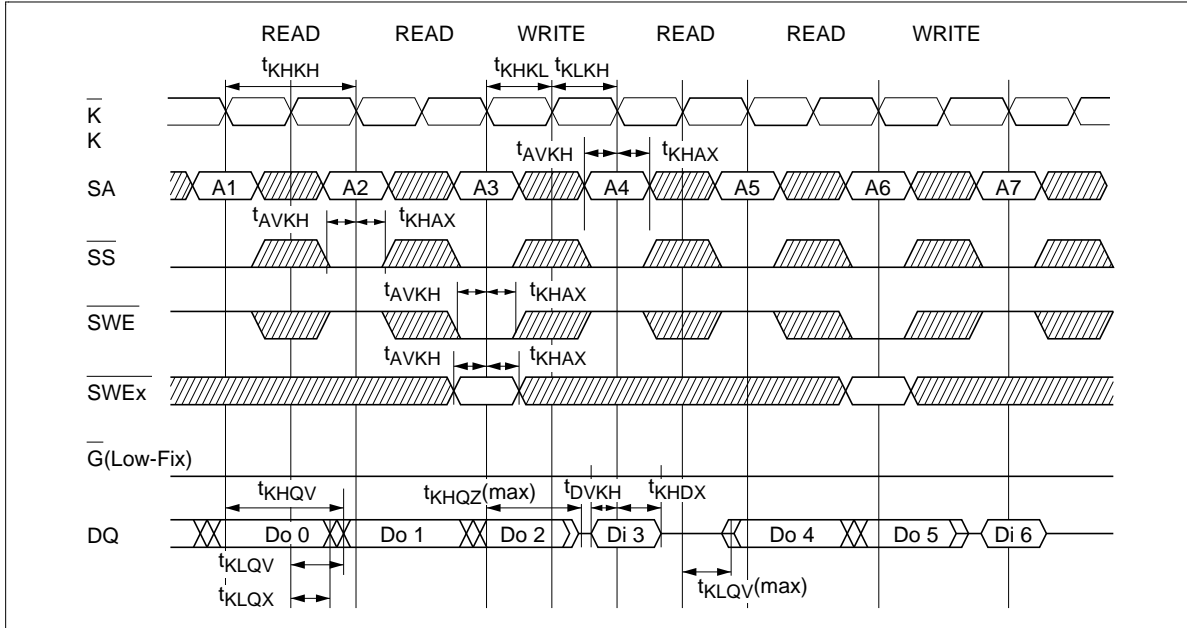


Write Cycle



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Read-Write Cycle



(1) During this period DQ pins are in the output state so that the input signal of opposite phase to the outputs must not be applied.

Boundary Scan Test Access Port Operations

overview

In order to perform the interconnect testing of the modules that include this SRAM, the serial boundary access port (TAP) is designed to operate in a manner consistent with IEEE Standard 1149.1 - 1990. But does not implement all of the functions required for 1149.1. the HM67S18258 contains a TAP controller. Instruction register, Boundary scan register, Bypass and ID register.

Test Access Port Pins

| Symbol I/O | Name |
|------------|------------------|
| TCK | Test Clock |
| TMS | Test Mode Select |
| TDI | Test Data In |
| TDO | Test Data Out |

Notes: This Device does not have a TRST (TAP Reset) pin. TRST is optional in IEEE 1149.1. To disable the TAP, TCK must be connected to V_{SS} . TDO should be left unconnected.

TAP DC Operating Characteristics ($T_a = 0^{\circ}\text{C}$ to 70°C [T_j max = 110°C])

| Parameter | Symbol | Min | Max | Note |
|-------------------------------------|----------|------------|------------------|------|
| Boundary scan Input High voltage | V_{IH} | 2.0 V | $V_{DD} + 0.3$ V | |
| Boundary scan Input Low voltage | V_{IL} | -0.5 V | 0.8 V | |
| Boundary scan Input Leakage Current | I_{LI} | -1 μ A | +1 μ A | 1 |
| Boundary scan Output Low voltage | V_{OL} | | 0.4 V | 2 |
| Boundary scan Output High voltage | V_{OH} | 2.4 V | | 3 |

Notes: 1. $0 \leq V_{in} \leq V_{DD}$
 2. $I_{OL} = 2$ mA
 3. $I_{OH} = -2$ mA

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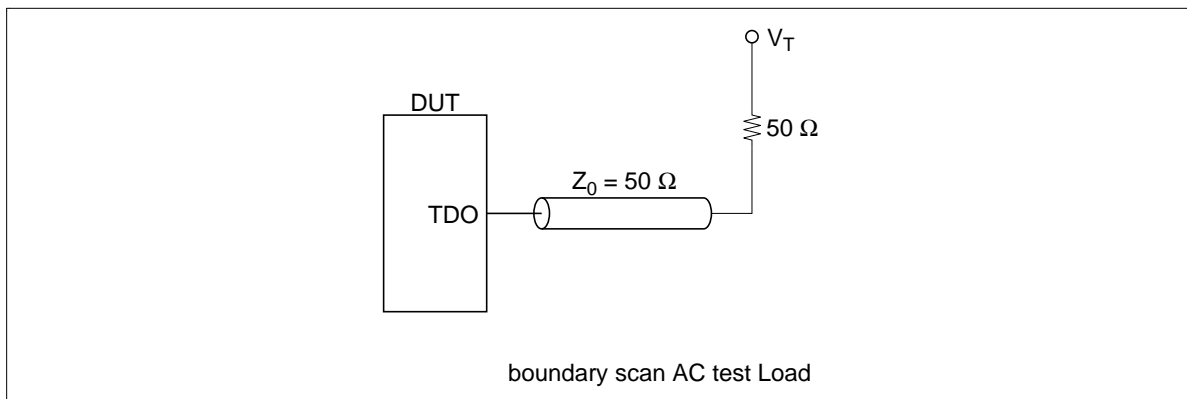
TAP AC Operating Characteristics (Ta = 0°C to 70°C [Tj max = 110 °C])

| Parameter | Symbol | Min | Max | Unit |
|-----------------------------|-------------------|-----|-----|------|
| Test Clock Cycle Time | t_{THTH} | 67 | — | ns |
| Test Clock High Pulse Width | t_{THTL} | 30 | — | ns |
| Test Clock Low Pulse Width | t_{TLTH} | 30 | — | ns |
| Test Mode Select Setup | t_{MVTH} | 10 | — | ns |
| Test Mode Select Hold | t_{THMX} | 10 | — | ns |
| Capture Setup | t_{CS} | 10 | — | ns |
| Capture Hold | t_{CH} | 10 | — | ns |
| TDI Valid to TCK High | t_{DVTH} | 10 | — | ns |
| TCK High to TDI Don't Care | t_{THDX} | 10 | — | ns |
| TCK Low to TDO Unknown | t_{TLQX} | 0 | — | ns |
| TCK Low to TDO Valid | t_{TLQV} | — | 20 | ns |

Notes: 1. $t_{\text{CS}} + t_{\text{CH}}$ defines the minimum pause in RAM I/O pad transitions to assure pad data capture.

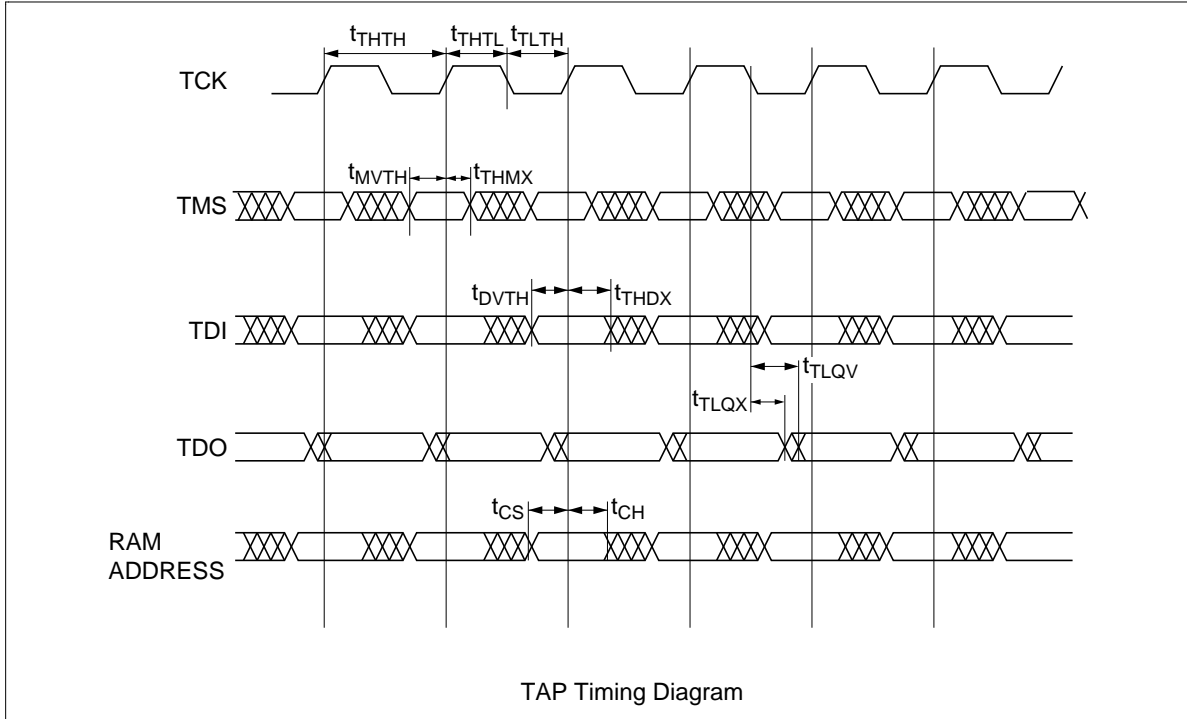
TAP AC Test Conditions

- Temperature $0^{\circ}\text{C} \leq T_a \leq 70^{\circ}\text{C}$ [T_j max = 110°C]
- Input Reference Point for Single-Ended Signals 1.5 V
- Input pulse levels 0 to 2.5 V
- Input Rise/Fall Time 2.0 ns typical (10% to 90%)
- Output timing reference 1.5 V
- Test load termination supply voltage (V_T) 1.5 V
- Output Load See figures



HM67S18258 Series

TAP Timing Diagram



Test Access Port Registers

| Register Name | Length | Symbol | Note |
|------------------------|---------------|---------------|-------------|
| Instruction Register | 3 bits | IR [0;2] | |
| Bypass Register | 1 bits | BP | |
| ID Register | 32 bits | ID [0;31] | |
| Boundary Scan Register | 51 bits | BS [1;51] | |

TAP Controller Instruction Set

| IR2 | IR1 | IR0 | Instruction | Operation |
|------------|------------|------------|--------------------|---|
| 0 | 0 | 0 | SAMPLE-Z | Tristate all data drivers and capture the pad value |
| 0 | 0 | 1 | IDCODE | |
| 0 | 1 | 0 | SAMPLE-Z | Tristate all data drivers and capture the pad value |
| 0 | 1 | 1 | BYPASS | |
| 1 | 0 | 0 | SAMPLE | |
| 1 | 0 | 1 | BYPASS | |
| 1 | 1 | 0 | BYPASS | |
| 1 | 1 | 1 | BYPASS | |

Note: This Device does not perform EXTEST, INTEST or the preload portion of the PRELOAD command in IEEE 1149.1.

HM67S18258 Series

Boundary Scan Order

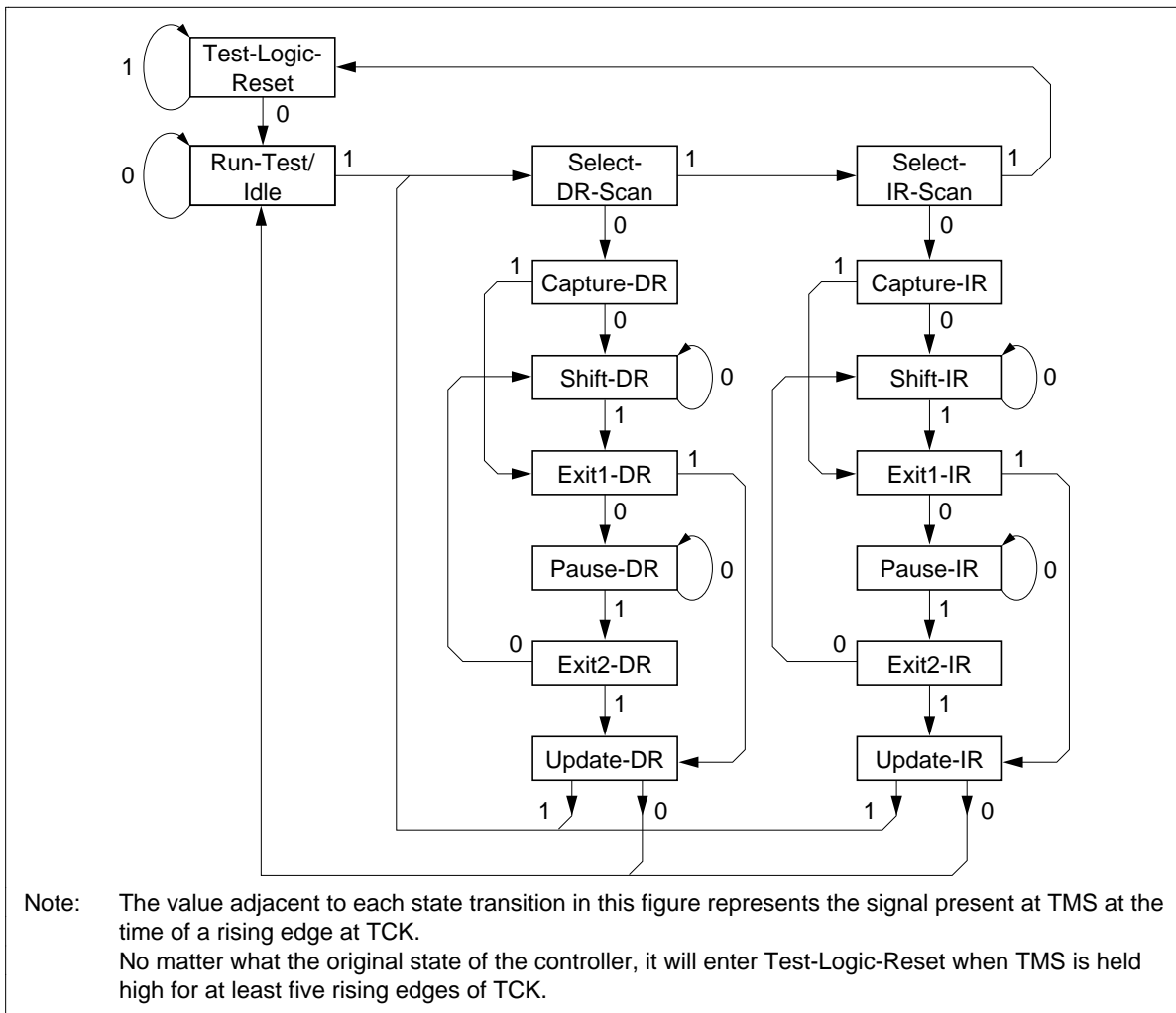
| Bit # | Bump ID | Signal Name | Bit # | Bump ID | Signal Name |
|-------|---------|--------------------------|-------|---------|--------------------------|
| 1 | 5R | M2 | 27 | 2B | NC |
| 2 | 6T | SA4 | 28 | 3A | SA14 |
| 3 | 4P | SA5 | 29 | 3C | SA15 |
| 4 | 6R | SA6 | 30 | 2C | SA16 |
| 5 | 5T | SA7 | 31 | 2A | SA17 |
| 6 | 7T | ZZ | 32 | 1D | DQc0 |
| 7 | 7P | DQa0 | 33 | 2E | DQc1 |
| 8 | 6N | DQa1 | 34 | 2G | DQc2 |
| 9 | 6L | DQa2 | 35 | 1H | DQc3 |
| 10 | 7K | DQa3 | 36 | 3G | $\overline{\text{SWEc}}$ |
| 11 | 5L | $\overline{\text{SWEa}}$ | 37 | 4D | NC |
| 12 | 4L | $\overline{\text{K}}$ | 38 | 4E | $\overline{\text{SS}}$ |
| 13 | 4K | K | 39 | 4G | NC |
| 14 | 4F | $\overline{\text{G}}$ | 40 | 4H | NC |
| 15 | 6H | DQa4 | 41 | 4M | $\overline{\text{SWE}}$ |
| 16 | 7G | DQa5 | 42 | 2K | DQc4 |
| 17 | 6F | DQa6 | 43 | 1L | DQc5 |
| 18 | 7E | DQa7 | 44 | 2M | DQc6 |
| 19 | 6D | DQa8 | 45 | 1N | DQc7 |
| 20 | 6A | SA8 | 46 | 2P | DQc8 |
| 21 | 6C | SA9 | 47 | 3T | SA0 |
| 22 | 5C | SA10 | 48 | 2R | SA1 |
| 23 | 5A | SA11 | 49 | 4N | SA2 |
| 24 | 6B | NC | 50 | 2T | SA3 |
| 25 | 5B | SA12 | 51 | 3R | M1 |
| 26 | 3B | SA13 | | | |

- Notes:
1. Bit#1 is the first scan bit to exit the chip.
 2. NC pads listed in the TABLE are represented in the Boundary Scan Register by a Place Holder. Place Holder registers are internally connected to V_{SS} .
 3. The clock pins (K and $\overline{\text{K}}$) are needed as PECL differential levels. And, clock receiver generated single clock signal. This signal and its inverted signal are used for Boundary Scan Register input signal.

ID register

| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|-------|---------------------|----|----|----|---------------|----|----|---------------|----|----|-------|----|-------------------|----|----|----|----|---------------|----|----|----|----|-----|---|---|---|---|---|---|---|---|---|
| Bit# | 31 | 30 | 29 | 28 | 27 | 26 | 25 | 24 | 23 | 22 | 21 | 20 | 19 | 18 | 17 | 16 | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| Value | X | X | X | X | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| | Vendor Revision No. | | | | 4M, 16M Depth | | | 4M, 16M Width | | | Width | | Use in the future | | | | | Vendor ID No. | | | | | Fix | | | | | | | | | |

TAP Controller State Diagram

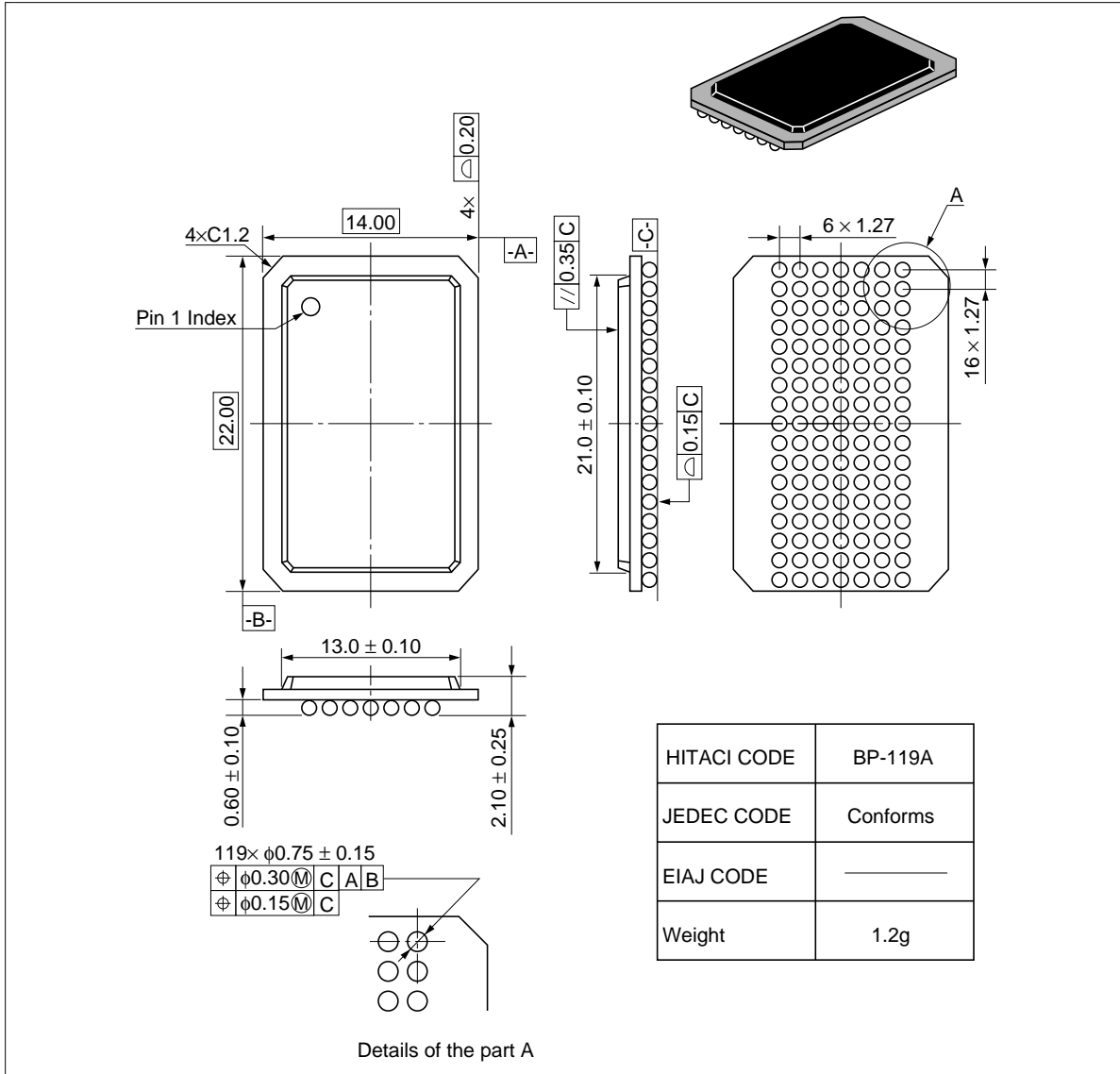


HM67S18258 Series

Package Outline

HM67S18258BP (BP-119A)

Unit : mm



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HM67S18258 Series

Revision Record

| Rev | Date | Contents of Modification | Drawn by | Approved by |
|-----|---------------|---|-------------|-------------|
| 0.0 | Oct. 1, 1996 | Initial issue | — | K.Mitsumoto |
| 1 | Feb. 21, 1997 | P1. 3.3V± 0.1V Operation to 3.3V± 5% Operation Change HM67S18258BP-7H to HM67S18258BP-7 V_{DDmin} 3.2 to 3.135 V_{DDmax} 3.4 to 3.465 V_{DDQmin} 3.2/.6 to 3.135/2.375 V_{DDQmax} 3.4/2.6 to 3.465/2.75 I_{DDmax} 500 to 600 I_{OH} 2mA to - 2mA I_{OL} - 2mA to 2mA P.7 Change termination load t_{KHKL} 3.2 to 2.0 t_{KCLKH} 3.2 to 2.0 Add $t_{KHQZmin}$ Add Note 2 Delete Soft Error Rate | (Y. Matsui) | S.Nakazato |
| 2 | Nov. 18, 1997 | BP-119 to BP-119A | (Y. Matsui) | S. Nakazato |